









SN74LV27A

SCES341F - SEPTEMBER 2000 - REVISED JULY 2023

SN74LV27A Triple 3-Input Positive-NOR Gate

1 Features

- Operation of 2-V to 5.5-V V_{CC}
- Max t_{nd} of 7 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) >2.3 V at $V_{CC} = 3.3 \text{ V}, \text{ TA} = 25^{\circ}\text{C}$
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

2 Description

These triple 3-input positive-NOR gates are designed for 2-V to 5.5-V V_{CC} operation.

The SN74LV27A devices perform the Boolean function $Y = \overline{A + B + C}$ in positive logic.

These devices are fully specified for partial-powerdown applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

Package Information

PART NUMBER	PACKAGE ¹	PACKAGE SIZE ²
	DGV (TVSOP, 14)	3.60 mm x 6.4 mm
	D (SOIC, 14)	8.65 mm x 6 mm
SN74LV27A	NS (SO, 14)	10.20 mm x 7.8 mm
	DB (SSOP, 14)	6.20 mm x 7.8 mm
	PW (TSSOP, 14)	5.00 mm x 6.4 mm

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.

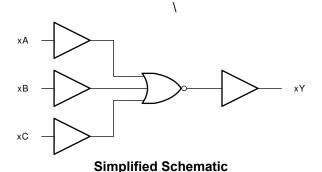




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3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (May 2005) to Revision F (July 2023)

Page

 Updated the numbering, formatting, tables, figures and cross-references throughout the document to reflect modern data sheet standards......



4 Pin Configuration and Functions

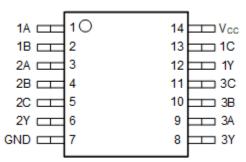


Figure 4-1. SN74LV27A D, NS, PW, DGV, or DB Package (Top View)

	PIN	TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.	ITPE	DESCRIPTION
1A	1	I	1A Input
1B	2	I	1B Input
2A	3	I	2A Input
2B	4	I	2B Input
2C	5	I	2C Input
2Y	6	0	2Y Output
3Y	8	0	3Y Output
3A	9	I	3A Input
3B	10	I	3B Input
3C	11	I	3C Input
1Y	12	0	1Y Output
1C	13	I	1C Input
GND	7	_	Ground Pin
V _{CC}	14	_	Power Pin

⁽¹⁾ Signal Types: I = Input, O = Output.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

				MIN	MAX	UNIT
V _{CC}	Supply voltage range			-0.5	7	V
VI	Input voltage range ⁽²⁾			-0.5	7	V
Vo	Output voltage range applied in h	nigh or low state ^{(2) (3)}		-0.5	V _{CC} + 0.5	V
Vo	Output voltage range applied in p	power-off state ⁽²⁾		-0.5	7	V
I _{IK}	Input clamp current	(V ₁ < 0)			-20	mA
I _{OK}	Output clamp current	(V _O < 0)			-50	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$			±25	mA
	Continuous current through V _{CC}	Continuous current through V _{CC} or GND			±50	mA
T _{stg}	Storage temperature			-65	150	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
\/·	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	± 2000	V
V _(ESD)	Liectiostatic discharge	Charged device model (CDM), per JESD22-C101 (2)	± 1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
		V _{CC} = 2 V	1.5		
V _{IH}	High level input voltage	V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7		V
	i ligit level litput voltage	V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		V
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7		
	Low level input voltage	V _{CC} = 2 V		0.5	
		V _{CC} = 2.3 V to 2.7 V		V _{CC} × 0.3	V
V _{IL}		V _{CC} = 3 V to 3.6 V		V _{CC} × 0.3	V
		V _{CC} = 4.5 V to 5.5 V		V _{CC} × 0.3	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 2 V		-50	μA
	High level output ourrent	V _{CC} = 2.3 V to 2.7 V		-2	
I _{OH}	High level output current	V _{CC} = 3 V to 3.6 V		-6	mA
		V _{CC} = 4.5 V to 5.5 V		-12	

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²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ This value is limited to 5.5 V maximum.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN MAX	UNIT
		V _{CC} = 2 V	50	μA
I _{OL} Low level outp	Lour lovel output ourrent	V _{CC} = 2.3 V to 2.7 V	2	
	Low level output current	V _{CC} = 3 V to 3.6 V	6	mA
		V _{CC} = 4.5 V to 5.5 V	12	
		V _{CC} = 2.3 V to 2.7 V	200	
Δt/Δν	Input transition rise and fall rate	V _{CC} = 3 V to 3.6 V	100	ns/V
		V _{CC} = 4.5 V to 5.5 V	20	
T _A	Operating free-air temperature		-40 85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004

5.4 Thermal Information

		SN74LV27A						
	THERMAL METRIC(1)	D NS PW DB DGV					UNIT	
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86	76	113	96	127	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
		Ι _{ΟΗ} = –50 μΑ	2 V to 5.5 V	V _{CC} - 0.1			
V	High-level output voltage	I _{OH} = -2 mA	2.3 V	2			V
V _{OH}		I _{OH} = -6 mA	3 V	2.48			V
		I _{OH} = -12 mA	4.5 V	3.8			
		I _{OL} = 50 μA	2 V to 5.5 V			0.1	
,,		I _{OL} = 2 mA	2.3 V			0.4	v
V _{OL}	Low-level output voltage	I _{OL} = 6 mA	3 V			0.44	V
		I _{OL} = 12 mA	4.5 V			0.55	
II	Input leakage current	V _I = 5.5 V or GND	0 to 5.5 V			±1	μA
I _{CC}	Supply current	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			20	μА
I _{off}	Off-state leakage current	V_I or $V_O = 0$ to 5.5 V	0 V			5	μA
Ci	Input capacitance	V _I = V _{CC} or GND	3.3 V		1.9		pF

5.6 Switching Characteristics, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	LOAD	7	Γ _A = 25°C		SN74L\	/27A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	
t _{pd}	A, B, or C	Y	C _L = 15 pF		6.7	13.8	1	16	ns
t _{pd}	A, B, or C	Y	C _L = 50 pF		9.5	17.5	1	21	115



5.7 Switching Characteristics, V_{CC} = 3.3 V ± 0.3 V

over recommended operating free-air temperature range (unless otherwise noted) (seeLoad Circuit and Voltage Waveforms)

DADAMETED	FROM	то	LOAD	Т	A = 25°C		SN74LV	27A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	UNII
t _{pd}	A, B, or C	Y	C _L = 15 pF		5	8.8	1	10.5	ne
t _{pd}	A, B, or C	Y	C _L = 50 pF		6.9	12.3	1	14	ns

5.8 Switching Characteristics, V_{CC} = 5 V ± 0.5 V

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	LOAD	Т	A = 25°C		SN74LV	′27A	UNIT	
PARAMETER	(INPUT)	(INPUT) (OUTPUT) CAPACITANCE		CAPACITANCE	MIN	TYP	MAX	MIN	MAX	
t _{pd}	A, B, or C	Y	C _L = 15 pF		3.9	5.9	1	7	ns	
t _{pd}	A, B, or C	Y	C _L = 50 pF		5.2	7.9	1	9	115	

5.9 Noise Characteristics

 V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C

	PARAMETER ⁽¹⁾	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		0	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		3.2		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

(1) Characteristics are for surface-mount packages only.

5.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST C	CONDITIONS	V _{cc}	TYP	UNIT
	Power dissipation capacitance	$C_1 = 50 \text{ pF},$	f = 10 MHz	3.3 V	13.7	nE
Cpd	Fower dissipation capacitance	CL = 50 pr,	1 - 10 WITZ	5 V	15	p⊦

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6 Parameter Measurement Information

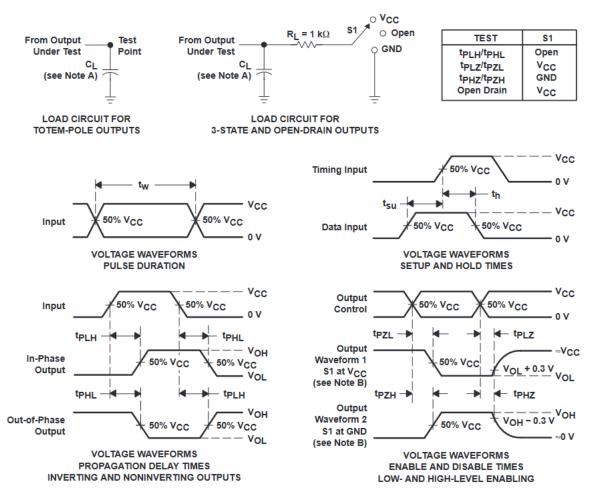


Figure 6-1. Load Circuit and Voltage Waveforms

- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.



7 Detailed Description

7.1 Overview

These triple 3-input positive-NOR gates are designed for 2-V to 5.5-V V_{CC} operation. The SN74LV27A devices perform the Boolean function $Y = \overline{A} + \overline{B} + \overline{C}$ in positive logic. These devices are fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

7.2 Functional Block Diagram

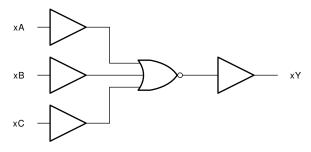


Figure 7-1. logic diagram, each gate (positive logic)

7.3 Device Functional Modes

Table 7-1. Function Table (Each Gate)

	INPUT ⁽¹⁾						
A	В	С	Υ				
Н	Х	X	L				
X	Н	X	L				
X	X	Н	L				
L	L	L	Н				

- (1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care
- (2) H = Driving High, L = Driving Low



8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Documentation Support (Analog)

8.1.1 Related Documentation

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74LV27A	Click here	Click here	Click here	Click here	Click here	

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV27AD	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	LV27A	
SN74LV27ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV27A	Samples
SN74LV27ADGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV27A	Samples
SN74LV27ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV27A	Samples
SN74LV27ANSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	74LV27A	Samples
SN74LV27APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	LV27A	Samples
SN74LV27APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV27A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV27ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LV27ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV27ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV27ANSR	SOP	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LV27APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV27APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV27APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV27APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV27ADBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74LV27ADGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74LV27ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV27ANSR	SOP	NS	14	2000	356.0	356.0	35.0
SN74LV27APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV27APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV27APWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV27APWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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